



Chipsmall Limited consists of a professional team with an average of over 10 year of expertise in the distribution of electronic components. Based in Hongkong, we have already established firm and mutual-benefit business relationships with customers from,Europe,America and south Asia,supplying obsolete and hard-to-find components to meet their specific needs.

With the principle of “Quality Parts,Customers Priority,Honest Operation,and Considerate Service”,our business mainly focus on the distribution of electronic components. Line cards we deal with include Microchip,ALPS,ROHM,Xilinx,Pulse,ON,Everlight and Freescale. Main products comprise IC,Modules,Potentiometer,IC Socket,Relay,Connector.Our parts cover such applications as commercial,industrial, and automotives areas.

We are looking forward to setting up business relationship with you and hope to provide you with the best service and solution. Let us make a better world for our industry!



## Contact us

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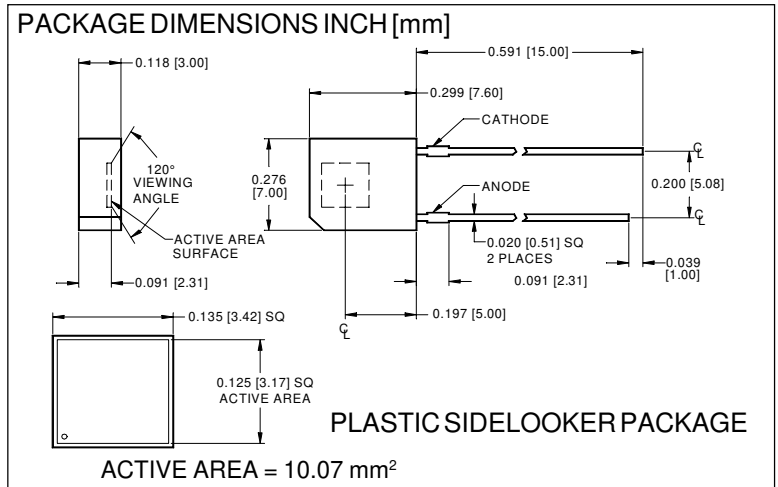
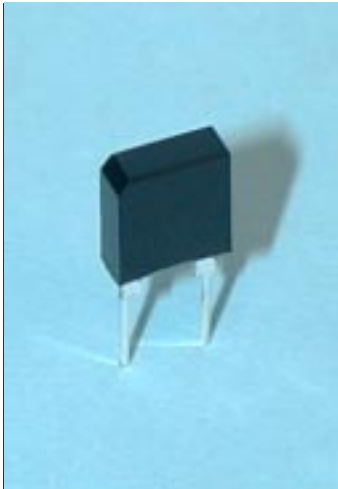
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# PHOTONIC DETECTORS INC.

## Silicon Photodiode, Blue Enhanced Photoconductive with daylight filter Type PDB-C159F



### FEATURES

- Large active area
- High speed
- Low cost

**DESCRIPTION:** The **PDB-C159F** detector is a 9.00 mm<sup>2</sup> planar pin photodiode packaged in a black plastic sidelooker housing. Designed for high speed, low capacitance, photoconductive applications. The **PDB-C159F** includes a daylight filter.

### APPLICATIONS

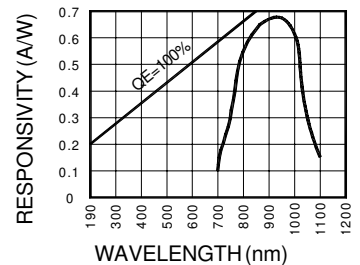
- I.R. links
- I.R. sensors
- I.R. remotes

### ABSOLUTE MAXIMUM RATING (TA=25°C unless otherwise noted)

SYMBOL	PARAMETER	MIN	MAX	UNITS
V <sub>BR</sub>	Reverse Voltage		50	V
T <sub>STG</sub>	Storage Temperature	-30	+100	°C
T <sub>O</sub>	Operating Temperature Range	-25	+85	°C
T <sub>S</sub>	Soldering Temperature*		+240	°C
I <sub>L</sub>	Light Current		500	mA

\*1/16 inch from case for 3 secs max

### SPECTRAL RESPONSE



### ELECTRO-OPTICAL CHARACTERISTICS (TA=25°C unless otherwise noted)

SYMBOL	CHARACTERISTIC	TEST CONDITIONS	MIN	TYP	MAX	UNITS
I <sub>SC</sub>	Short Circuit Current	H = 100 fc, 2850 K	59	68		μA
I <sub>D</sub>	Dark Current	H = 0, V <sub>R</sub> = 10 V		5	30	nA
R <sub>SH</sub>	Shunt Resistance	H = 0, V <sub>R</sub> = 10 mV	75	100		MΩ
TCR <sub>SH</sub>	RSH Temp. Coefficient	H = 0, V <sub>R</sub> = 10 mV		-8		% / °C
C <sub>J</sub>	Junction Capacitance	H = 0, V <sub>R</sub> = 10 V*		15	20	pF
λrange	Spectral Application Range	(with daylight filter)	700		1100	nm
λp	Spectral Response - Peak			950		nm
V <sub>BR</sub>	Breakdown Voltage	I = 10 μA	25	30		V
NEP	Noise Equivalent Power	V <sub>R</sub> = 10 V @ Peak		7x10 <sup>-13</sup>		W/√Hz
tr	Response Time	RL = 1 KΩ V <sub>R</sub> = 10 V		50		nS

Information in this technical data sheet is believed to be correct and reliable. However, no responsibility is assumed for possible inaccuracies or omission. Specifications are subject to change without notice. \*f = 1 MHz,

[FORM NO. 100-PDB-C159 REV A]